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## FQP47P06 P-Channel QFET<sup>®</sup> MOSFET

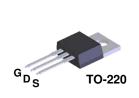
## - 60 V, - 47 A, 26 mΩ

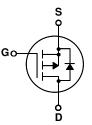
### Description

This P-Channel enhancement mode power MOSFET is produced using Fairchild Semiconducto®'s proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, audio amplifier, DC motor control, and variable switching power applications.

### Features

- 47 A, 60 V,  $R_{DS(on)}$  = 26 m $\Omega$  @ V\_{GS} = 10 V,  $I_{\rm D}$  = 23.5 A
- Low Gate Charge (Typ. 84 nC)
- Low Crss (yp. 320 pF)
- 100% Avalanche Tested
- 175°C Maximum Junction Temrature Rating.





## Absolute Maximum Ratings T<sub>c</sub> = 25°C unless otherwise noted

Symbol	Parameter		FQP47P06	Unit
V <sub>DSS</sub>	Drain-Source Voltage		-60	V
I <sub>D</sub>	Drain Current - Continuous (T <sub>C</sub> = 25°	°C)	-47	A
	- Continuous (T <sub>C</sub> = 100°C)		-33.2	Α
I <sub>DM</sub>	Drain Current - Pulsed	(Note 1)	-188	А
V <sub>GSS</sub>	Gate-Source Voltage		± 25	V
E <sub>AS</sub>	Single Pulsed Avalanche Energy	(Note 2)	820	mJ
I <sub>AR</sub>	Avalanche Current	(Note 1)	-47	Α
E <sub>AR</sub>	Repetitive Avalanche Energy	(Note 1)	16	mJ
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	-7.0	V/ns
PD	Power Dissipation ( $T_C = 25^{\circ}C$ )		160	W
	- Derate above 25°C		1.06	W/°C
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range		-55 to +175	°C
TL	Maximum lead temperature for soldering purposes,		300	°C
	1/8" from case for 5 seconds		500	

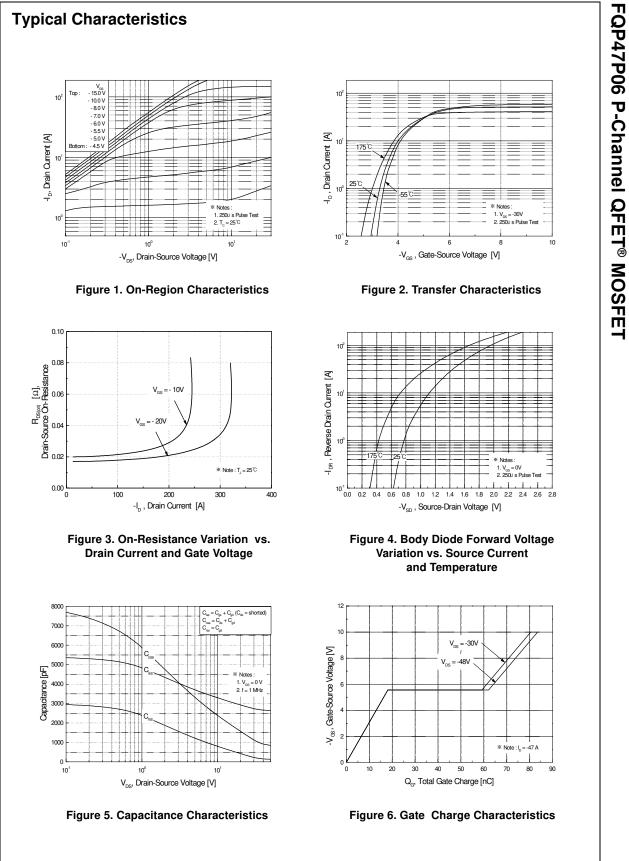
## **Thermal Characteristics**

Symbol	Parameter	FQP47P06	Unit
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	0.94	°C/W
$R_{\theta CS}$	Thermal Resistance, Case-to-Sink, Typ.	0.5	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient, Max.	62.5	°C/W

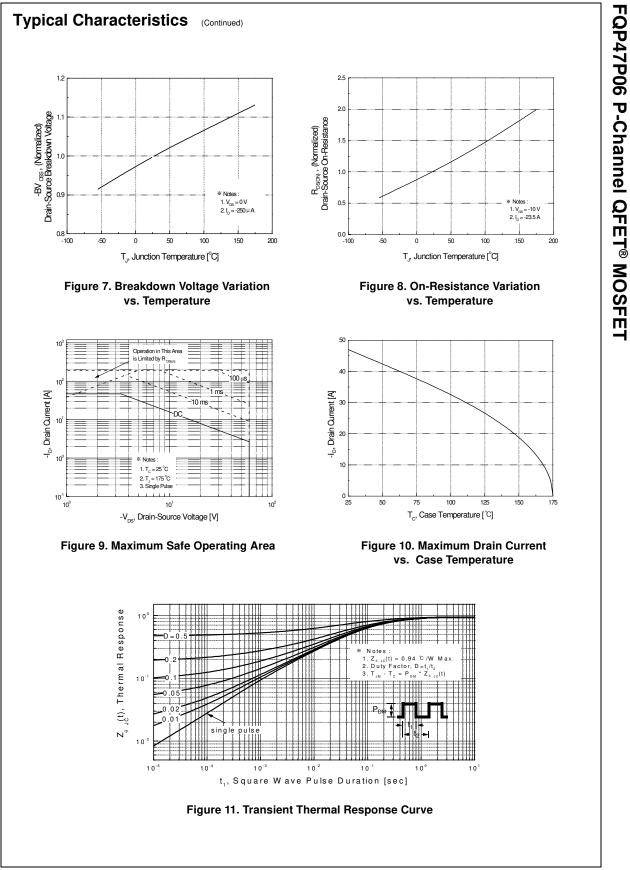
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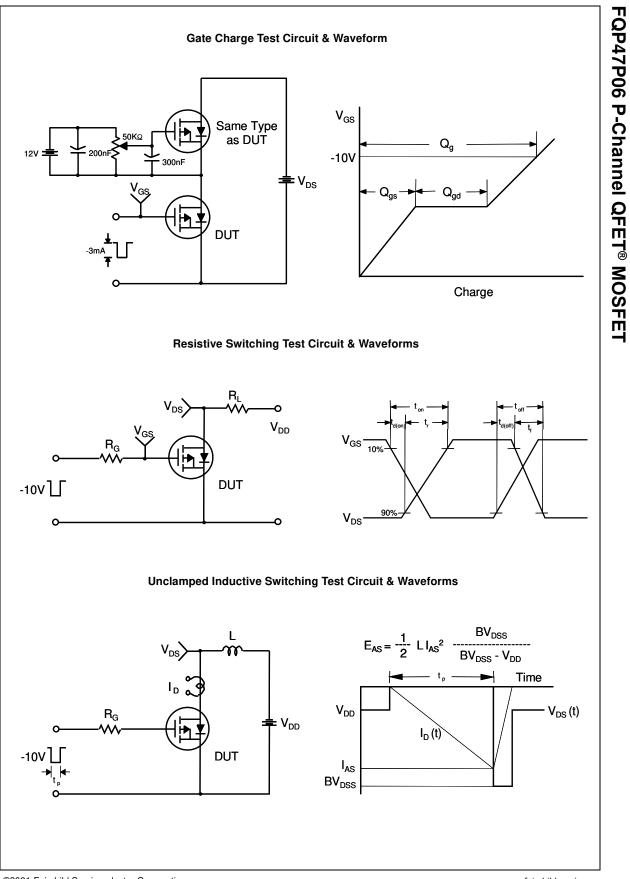
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Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
Off Cha	racteristics					
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0 V, I <sub>D</sub> = -250 μA	-60			V
ΔT <sub>.1</sub>	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$ , Referenced to 25°C		-0.06		V/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = -60 \text{ V}, V_{GS} = 0 \text{ V}$			-1	μA
		V <sub>DS</sub> = -48 V, T <sub>C</sub> = 150°C			-10	μA
GSSF	Gate-Body Leakage Current, Forward	$V_{GS} = -25 V, V_{DS} = 0 V$			-100	nA
GSSR	Gate-Body Leakage Current, Reverse	$V_{GS} = 25 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			100	nA
On Cha	racteristics					
/ <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = -250 μA	-2.0		-4.0	V
R <sub>DS(on)</sub>	Static Drain-Source On-Resistance	V <sub>GS</sub> = -10 V, I <sub>D</sub> = -23.5 A		0.021	0.026	Ω
FS	Forward Transconductance	V <sub>DS</sub> = -30 V, I <sub>D</sub> = -23.5 A (Note 4)		21		S
Viss Voss Vrss	Input Capacitance Output Capacitance Reverse Transfer Capacitance	$V_{DS} = -25 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1.0 MHz	 	2800 1300 320	3600 1700 420	pF pF pF
Switchi	ng Characteristics					
d(on)	Turn-On Delay Time	V <sub>DD</sub> = -30 V, I <sub>D</sub> = -23.5 A,		50	110	ns
r	Turn-On Rise Time	$R_G = 25 \Omega$		450	910	ns
d(off)	Turn-Off Delay Time	3		100	210	ns
f	Turn-Off Fall Time	(Note 4, 5)		195	400	ns
ג <sub>g</sub>	Total Gate Charge	$V_{DS} = -48 \text{ V}, I_{D} = -47 \text{ A},$		84	110	nC
¢ <sub>gs</sub>	Gate-Source Charge	V <sub>GS</sub> = -10 V		18		nC
ג <sub>gd</sub>	Gate-Drain Charge	(Note 4, 5)		44		nC
Jrain-9	ource Diode Characteristics ar	nd Maximum Ratings				
s	Maximum Continuous Drain-Source Dic				-47	А
SM	Maximum Pulsed Drain-Source Diode F	Forward Current			-188	A
/ <sub>SD</sub>	Drain-Source Diode Forward Voltage	V <sub>GS</sub> = 0 V, I <sub>S</sub> = -47 A			-4.0	V
rr	Reverse Recovery Time	$V_{GS} = 0 V, I_S = -47 A,$		130		ns
ر ارد	Reverse Recovery Charge	$dI_F / dt = 100 \text{ A}/\mu \text{s}$ (Note 4)		0.55		μC
L = 0.43mH, $S_{SD} \le -47$ A, Pulse Test :	ating : Pulse width limited by maximum junction temper $I_{AS} = -47A$ , $V_{DD} = -25V$ , $R_G = 25 \Omega$ , Starting $T_J = 25^{\circ}C$ $di/dt \le 300A/\mu_S$ , $V_{DD} \le BV_{DSS}$ , Starting $T_J = 25^{\circ}C$ Pulse width $\le 300\mu_S$ , Duty cycle $\le 2\%$ adependent of operating temperature					



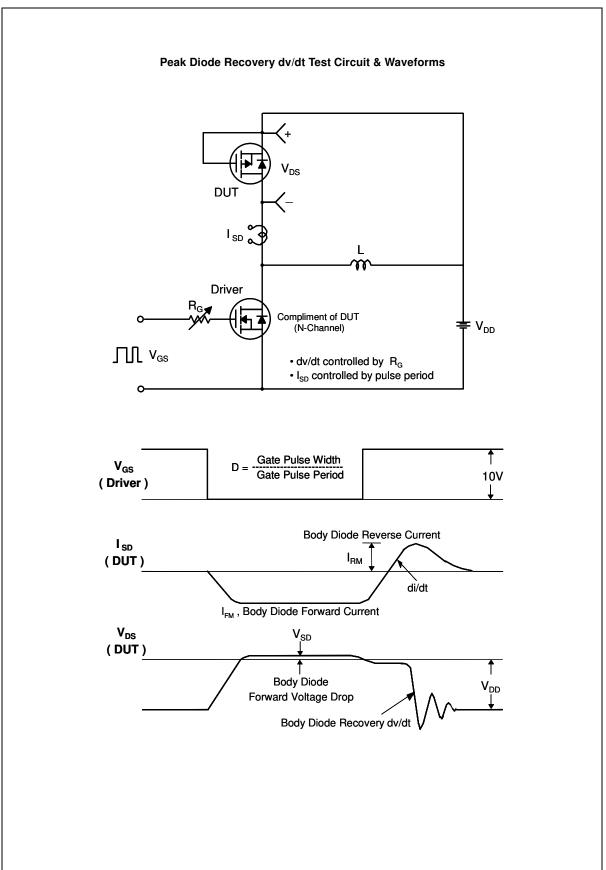
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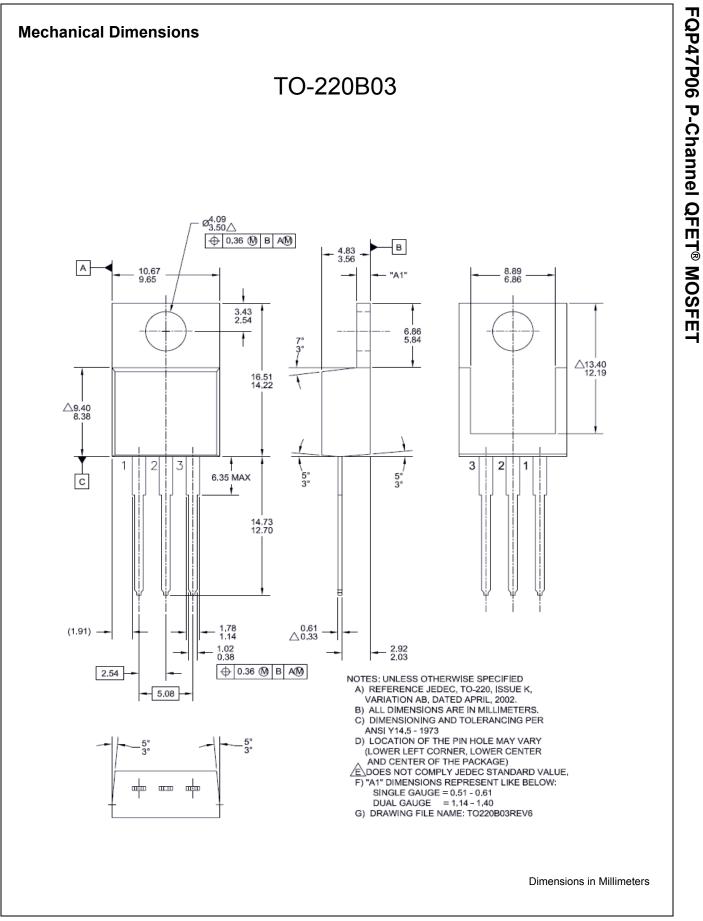


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